RT1N151X SERIES

(Transistor)

UNIT: mm

Transistor With Resistor For Switching Application Silicon NPN Epitaxial Type

DESCRIPTION

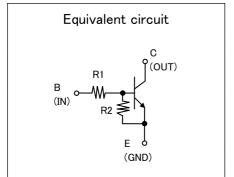
RT1N151X is a one chip transistor with built-in bias resistor,PNP type is RT1P151X.

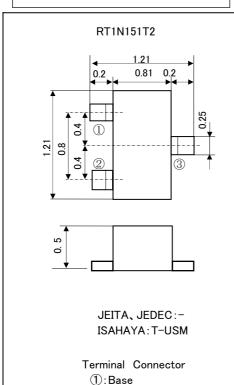
FEATURE

•Built-in bias resistor (R1=100k Ω ,R2=1 $\overline{00k}\Omega$).

APPLICATION

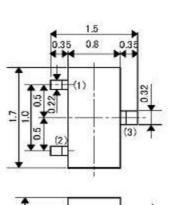
Inverted circuit, switching circuit, interface circuit, driver circuit.



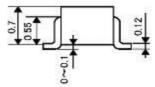


2: Emitter

3: Collector



RT1N151U

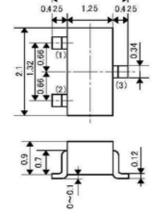


JEITA: — JEDEC: —

Terminal Connector

- ①:Base
- 2: Emitter
- 3: Collector

RT1N151M



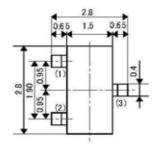


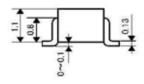
Terminal Connector

- (1):Base
- 2: Emitter
- ③: Collector

OUTLINE DRAWING

RT1N151C



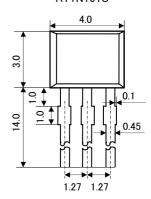


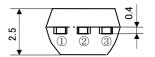
JEITA: SC-59 JEDEC: Similar to TO-236

Terminal Connector

- 1:Base
- 2:Emitter
- 3: Collector

RT1N151S





JEITA: — JEDEC: —

Terminal Connector

- ①:Emitter
- 2: Collector
- ③:Base

RT1N151X SERIES

(Transistor)

Transistor With Resistor
For Switching Application
Silicon NPN Epitaxial Type

MAXIMUM RATING (Ta=25°C)

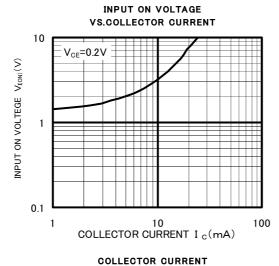
SYMBOL	PARAMETER	RATING					
		RT1N151T2	RT1N151U	RT1N151M	RT1N151C	RT1N151S	UNIT
V _{CBO}	Collector to Base voltage	50					
V _{EBO}	Emitter to Base voltage	10					
V _{CEO}	Collector to Emitter voltage	50					
Ιc	Collector current	100					
I _{CM}	Peak Collector current	200					mA
P _c	Collector dissipation(Ta=25°C)	(※)125	150	2	200	450	mW
Tj	Junction temperature	+125	+150				
Tstg	Storage temperature	−55 ~ +125	+125 -55~+150				

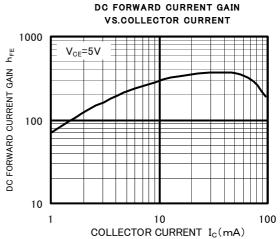
ELECTRICAL CHARACTERISTICS (Ta=25°C)

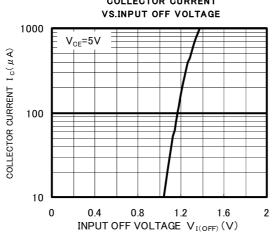
 $(\mbox{\ensuremath{\cancel{\times}}})$ package mounted on $9\mbox{mm}\times19\mbox{mm}\times1\mbox{mm}$ glass-epoxy substrate.

SYMBOL	PARAMETER	TEST CONDITION	LIMIT			UNIT
		TEST CONDITION	MIN	TYP	MAX	UNIT
$V_{(BR)CEO}$	C to E break down voltage	$I_{C}=100 \mu A, R_{BE}=\infty$	50			V
I _{CBO}	Collector cut off current	V_{CB} =50V, I_E =0			0.1	μΑ
h _{FE}	DC forward current gain	V_{CE} =5V, I $_{C}$ =5mA	82			_
$V_{CE(sat)}$	C to E saturation voltage	I_{C} =5mA, I_{B} =0.25mA		0.1	0.3	V
$V_{I(ON)}$	Input on voltage	V_{CE} =0.2V, I $_{C}$ =5mA		2.4	8.8	V
$V_{I(OFF)}$	Input off voltage	V_{CE} =5V, I $_{C}$ =100 μ A	0.8	1.1		V
R ₁	Input resistance			100		kΩ
R ₂ /R ₁	Resistance ratio		0.8	1.0	1.2	
f⊤	Gain band width product	V _{CE} =6V, I _E =-10mA		200		MHz

TYPICAL CHARACTERISTICS









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